

2N6317 Information



For Reference Only

Part Number 2N6317

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS PNP 60V 7A TO-213AA

Package TO-213AA, TO-66-2

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2N6317 Specifications

Manufacturer Part Number	2N6317
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-213AA, TO-66-2
Series	-
Transistor Type	PNP
Current - Collector (Ic) (Max)	7A
Voltage - Collector Emitter Breakdown (Max)	60V
Vce Saturation (Max) @ Ib, Ic	2V @ 1.75A, 7A
Current - Collector Cutoff (Max)	500μΑ
DC Current Gain (hFE) (Min) @ Ic, Vce	25 @ 2.5A, 4V
Power - Max	90W
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-213AA, TO-66-2
Supplier Device Package	-
	Report errors?

2N6317 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2N6317 Payment Methods



















2N6317 Shipping Methods













If you have any question about 2N6317, please do not hesitate to contact us!

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